

SPICE Device Model SUD50N06-07L Vishay Siliconix

N-Channel 60-V (D-S) 175°C MOSFET

CHARACTERISTICS

- N-Channel Vertical DMOS
- · Macro Model (Subcircuit Model)
- Level 3 MOS

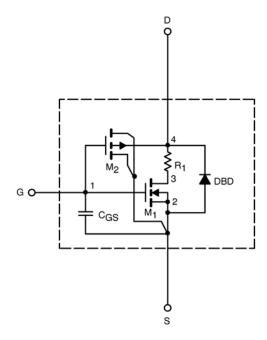
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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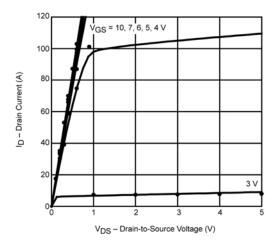
SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static			-		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.8		V
On-State Drain Current ^a	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	816		А
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = 10 V , I_D = 20 A	0.0059	0.0061	Ω
		V_{GS} = 10 V, I_{D} = 20 A, T_{J} = 125°C	0.0089		
		V _{GS} = 10 V, I _D = 20 A, T _J = 175°C	0.0105		
		V _{GS} = 4.5 V, I _D = 20 A	0.0067	0.0071	
Forward Voltage ^a	V_{SD}	$I_F = 30 \text{ A}, V_{GS} = 0 \text{ V}$	0.90	0.90	V
Dynamic ^b	<u> </u>		-		
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 25 V, f = 1 MHz	5755	5800	pF
Output Capacitance	C _{oss}		507	450	
Reverse Transfer Capacitance	C _{rss}		274	300	
Total Gate Charge ^c	Q_g	V _{DS} = 30 V, V _{GS} = 10 V, I _D = 50 A	95	96	nC
Gate-Source Charge ^c	Q _{gs}		19	19	
Gate-Drain Charge ^c	Q_{gd}		20	20	
Turn-On Delay Time ^c	t _{d(on)}	$V_{DD} = 30 \text{ V}, R_L = 0.60 \Omega$ $I_D \cong 50 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 2.5 \Omega$	16	15	ns
Rise Time ^c	t _r		9	13	
Turn-Off Delay Time ^c	t _{d(off)}		45	62	
Fall Time ^c	t _f		12	14	

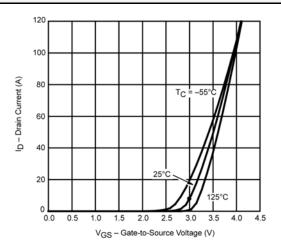
- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.

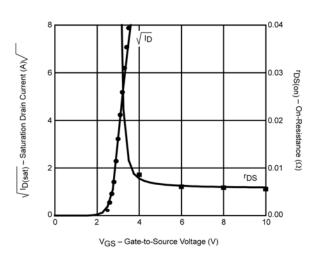


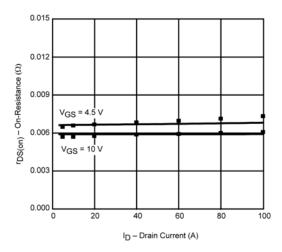
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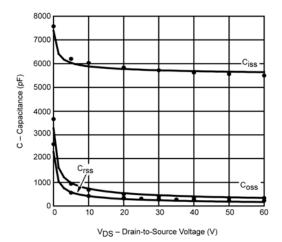
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

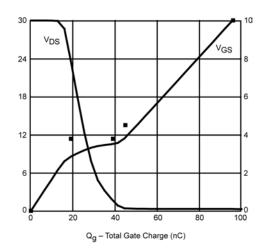












Note: Dots and squares represent measured data.





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